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APPLICATION NO. FILING DATE FIRST NAMED INVENTOR ATTORNEY DOCKET NO. CONFIRMATION NO. 10/751,443 01/06/2004 Hongmei Wang M4065.0536/P536-B 2565 EXAMINER 24998 7590 03/16/2006 DICKSTEIN SHAPIRO MORIN & OSHINSKY LLP PIZARRO CRESPO, MARCOS D 2101 L Street, NW **ART UNIT** PAPER NUMBER Washington, DC 20037 2814 DATE MAILED: 03/16/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

4	Application No.	Applicant(s)
	10/751,443	WANG ET AL.
Office Action Summary	Examiner	Art Unit
	Marcos D. Pizarro-Crespo	2814
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply		
A SHORTENED STATUTORY PERIOD FOR F WHICHEVER IS LONGER, FROM THE MAILII  Extensions of time may be available under the provisions of 37 of after SIX (6) MONTHS from the mailing date of this communicat.  If NO period for reply is specified above, the maximum statutory.  Failure to reply within the set or extended period for reply will, by Any reply received by the Office later than three months after the earned patent term adjustment. See 37 CFR 1.704(b).	NG DATE OF THIS COMMUNICA CFR 1.136(a). In no event, however, may a replication. period will apply and will expire SIX (6) MONTHY statute, cause the application to become ABAN	ATION.  ly be timely filed  IS from the mailing date of this communication.  NDONED (35 U.S.C. § 133).
Status		
<ul> <li>1) ⊠ Responsive to communication(s) filed on</li> <li>2a) ☐ This action is FINAL.</li> <li>2b) ☒</li> <li>3) ☐ Since this application is in condition for a closed in accordance with the practice un</li> </ul>	This action is non-final. Ilowance except for formal matter	
Disposition of Claims		
4) ☐ Claim(s) 27 and 32-35 is/are pending in the same state of the above claim(s) is/are with signal of the above claim(s) is/are allowed.  6) ☐ Claim(s) 27 and 32-35 is/are rejected.  7) ☐ Claim(s) is/are objected to.  8) ☐ Claim(s) are subject to restriction	thdrawn from consideration.	
Application Papers		
9) The specification is objected to by the Ext.  10) The drawing(s) filed on <u>06 January 2004</u> Applicant may not request that any objection  Replacement drawing sheet(s) including the second of the following the second of the following the second of the	is/are: a) ☐ accepted or b) ☒ obj to the drawing(s) be held in abeyance correction is required if the drawing(s	e. See 37 CFR 1.85(a). ) is objected to. See 37 CFR 1.121(d).
Priority under 35 U.S.C. § 119		
12) Acknowledgment is made of a claim for for a) All b) Some * c) None of:  1. Certified copies of the priority docu 2. Certified copies of the priority docu 3. Copies of the certified copies of the application from the International E * See the attached detailed Office action for	uments have been received. uments have been received in Appe e priority documents have been re Bureau (PCT Rule 17.2(a)).	plication No eceived in this National Stage
Attachment(s)  1) Notice of References Cited (PTO-892)  2) Notice of Draftsperson's Patent Drawing Review (PTO-9-3) Information Disclosure Statement(s) (PTO-1449 or PTO/Paper No(s)/Mail Date	48) Paper No(s)/	mmary (PTO-413) Mail Date ormal Patent Application (PTO-152) -

Page 2 Application/Control Number: 10/751,443 (Non-Final Rejection)

Art Unit: 2814

Attorney's Docket Number: M4065.0536/P536-B

Filing Date: 1/6/2004

Claimed Priority Dates: 11/26/2002 (Continuation of 10/303,696)

6/5/2002 (Divisional of 10/161,615)

Applicant(s): Wang, et al.

Examiner: Marcos D. Pizarro-Crespo

### **DETAILED ACTION**

This Office action responds to the amendment and declaration filed on 12/12/2005.

## Acknowledgment

The amendment and declaration filed on 5/19/2005, responding to the Office 1. action mailed on 6/10/2005, has been entered. The present Office action is made with all the suggested amendments being fully considered. Accordingly, pending in this Office action are claims 27 and 32-35.

## **Drawings**

- The drawings are objected to as failing to comply with 37 CFR 1.84(p)(5) 2. because they do not include the following reference sign(s) mentioned in the description (see, e.g., par.0041/II.6) with respect to figure 19: **100**.
- Corrected drawing sheets in compliance with 37 CFR 1.121(d) are required in 3. reply to the Office action to avoid abandonment of the application. Any amended replacement-drawing sheet should include all of the figures appearing on the immediate prior version of the sheet, even if only one figure is being amended. The figure or figure number of an amended drawing should not be labeled as "amended." If a drawing figure is to be canceled, the appropriate figure must be removed from the replacement sheet,

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and where necessary, the remaining figures must be renumbered and appropriate changes made to the brief description of the several views of the drawings for consistency. Additional replacement sheets may be necessary to show the renumbering of the remaining figures. Each drawing sheet submitted after the filing date of an application must be labeled in the top margin as either "Replacement Sheet" or "New Sheet" pursuant to 37 CFR 1.121(d). If the examiner does not accept the changes, the applicant will be notified and informed of any required corrective action in the next Office action. The objection to the drawings will not be held in abeyance.

## Claim Rejections - 35 USC § 103

- 4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 5. This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary.
- 6. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

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- 7. Claims 27, 32, and 33 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yu (US 6484065) in view of Houston (US 6424016) and King (US 6754104).
- 8. Regarding claim 27, Yu (see, e.g., fig. 1) shows most aspects of the instant invention including a processor-based system **100** comprising
  - > A processor 110
- ➤ An integrated circuit **120** coupled to the processor **110**wherein the circuit comprises a transistor, the transistor comprising source/drain regions of a first conductivity type and a gate stack including a conductive layer.

Although not explicit, Yu shows the circuit including DRAM banks **120a-d**, which by definition are made of transistors, each with its respective first-conductivity-type source/drain regions and conductive-layer gate stack.

Yu, however, fails to specify that the source/drain regions and the gate stack be provided on an SOI substrate and that the conductive layer of the gate stack is of a second conductivity type.

Houston (see, e.g., col.1/II.14-25), on the other hand, teaches that SOI substrates are good for DRAMs for several reasons. One reason is that SOIs have lower collection volumes.

Like Yu, Houston (see, e.g., figs. 5-6 and col.4/II.54-58) also shows DRAMs including transistors having source/drain regions of a first conductivity type (n-type) and a gate stack **40** including a conductive layer of a second conductivity type (p-type).

These are fully depleted SOI NMOS **40 41** forming part of a memory array (see, e.g., col.5/II.52-53).

Houston also shows a partially depleted SOI NMOS transistor **42** comprising source/drain regions provided on the substrate. The source/drain regions are of n-type conductivity (see, *e.g.*, col.5/II.54-56 and col.6/II.7-9). A second gate stack is fabricated on the substrate including a conductive layer of a p-type conductivity (see, *e.g.*, col.5/II.50-51).

It would have been obvious at the time of the invention to one of ordinary skill in the art to have Yu's integrated circuit comprising fully-depleted and partially-depleted transistors having gate stacks and source/drain regions provided on an SOI substrate, wherein the gate stacks are p-type and the source/drain regions are n-type, as suggested by Houston, to lower the collection volume of the integrated circuit.

Yu/Houston teach using polysilicon as the gate material (see, *e.g.*, Houston/col.5/II.50-60) but fail to teach using silicon/germanium. King, on the other hand, teaches (see, *e.g.*, col.15/II.20-30) that polysilicon and silicon/germanium are equivalents for their use as gate materials.

Therefore, because polysilicon and silicon/germanium were recognized in the art at the time of the invention as equivalents for their use as gate materials, one of ordinary skill in the art would have found it obvious to substitute Yu/Houston's doped polysilicon for the silicon/germanium that King suggested.

9. Regarding claim 32, Houston shows that the conductive layer of the gate stack is a doped polysilicon layer (see, e.g., col.5/II.50).

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- 10. Regarding claim 33, King teaches that the conductive layer is silicon/germanium (see, e.g., col/15/II.20-30).
- 11. Claims 34 and 35 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yu/Houston/King in view of Wu (US 6060749).
- 12. Regarding claims 34 and 35, Yu/Houston/King show most aspects of the instant invention (see, *e.g.*, paragraph 8 above), except for at least one of the gate stacks further comprising a silicide layer or a cap layer over the conductive layer.

Wu (see, e.g., col.5/II.9-18), on the other hand, teaches that having a silicide cap layer over Yu/Houston/King's gate will reduce the parasitic resistance of the gate.

It would have been obvious at the time of the invention to one of ordinary skill in the art to form a silicide cap layer over Yu/Houston/King's conductive layer, as suggested by Wu, to reduce the parasitic resistance of the gate.

#### Response to Declaration

13. The declaration filed on 12/12/2005 under 37 CFR 1.131 is sufficient to overcome the Krivokapic reference (US 6452229).

### Response to Arguments

14. Applicant's arguments with respect to the claims have been considered but are most in view of the new ground(s) of rejection.

#### Conclusion

15. Papers related to this application may be submitted directly to Art Unit 2814 by facsimile transmission. Papers should be faxed to Art Unit 2814 via the Art Unit 2814 Fax Center. The faxing of such papers must conform to the notice published in the

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Official Gazette, 1096 OG 30 (15 November 1989). The Art Unit 2814 Fax Center number is (571) 273-8300. The Art Unit 2814 Fax Center is to be used only for papers related to Art Unit 2814 applications.

- 16. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Marcos D. Pizarro-Crespo at (571) 272-1716 and between the hours of 9:30 AM to 8:00 PM (Eastern Standard Time) Monday through Thursday or by e-mail via <a href="Marcos.Pizarro@uspto.gov">Marcos.Pizarro@uspto.gov</a>. If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wael Fahmy, can be reached on (571) 272-1705.
- 17. Any inquiry of a general nature or relating to the status of this application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

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# 18. The following list is the Examiner's field of search for the present Office Action:

Field of Search	Date
U.S. Class / Subclass(es): 257/347-354,407	1/23/2006
Other Documentation: PLUS Analysis	3/15/2005
Electronic Database(s): EAST (USPAT, EPO, JPO)	1/23/2006

Marcos D. Pizarro-Crespo

Patent Examiner Art Unit 2814 571-272-1716

marcos.pizarro@uspto.gov

MDP/mdp February 28, 2006

#### Application/Control No. Applicant(s)/Patent Under Reexamination 10/751,443 WANG ET AL. Notice of References Cited Art Unit Examiner Page 1 of 1 2814 Marcos D. Pizarro-Crespo **U.S. PATENT DOCUMENTS Document Number** Date Name Classification Country Code-Number-Kind Code MM-YYYY US-6,754,104 06-2004 King, Tsu-Jae 365/185.14 Α US-В US-С US-D US-Ε US-F G US-US-Н US-US-J US-K US-L М US-FOREIGN PATENT DOCUMENTS **Document Number** Date Country Name Classification Country Code-Number-Kind Code MM-YYYY Ν 0 Ρ Q R S Т **NON-PATENT DOCUMENTS** Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages) U ٧ W

\*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).) Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.

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